

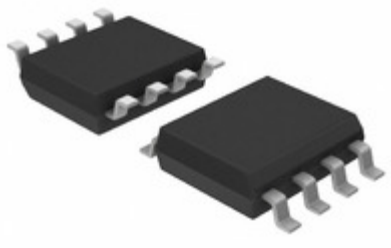


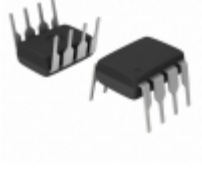
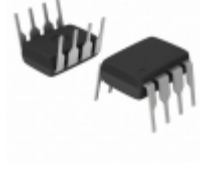
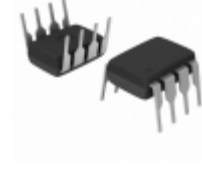

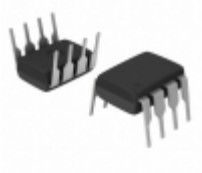
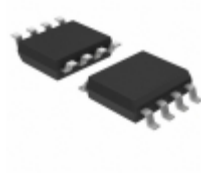


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|  <p>ADVANCED LINEAR DEVICES, INC.</p> | <p>ALD1117SAL</p> |
| | <p>Hersteller-Teilenummer: ALD1117SAL</p> <p>Hersteller / Marke: Advanced Linear Devices, Inc.</p> <p>Teil der Beschreibung: MOSFET 2P-CH 10.6V 8SOIC</p> <p>Datenblätter:  ALD1117SAL.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
|  <p><small>Image may be representation. See specs for product details.</small></p> | |

Spezifikationen

| | |
|--|---|
| Teilenummer | ALD1117SAL |
| Hersteller | Advanced Linear Devices, Inc. |
| Beschreibung | MOSFET 2P-CH 10.6V 8SOIC |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | Require For Quote & Check Stock |
| VGS (th) (Max) @ Id | 1V @ 1μA |
| Supplier Device-Gehäuse | 8-SOIC |
| Serie | - |
| Rds On (Max) @ Id, Vgs | 1800 Ohm @ 5V |
| Leistung - max | 500mW |
| Verpackung | Tube |
| Verpackung / Gehäuse | 8-SOIC (0.154", 3.90mm Width) |
| Betriebstemperatur | 0°C ~ 70°C (TJ) |
| Befestigungsart | Surface Mount |
| Eingabekapazität (Ciss) (Max) @ Vds | 3pF @ 5V |
| Gate Charge (Qg) (Max) @ Vgs | - |
| Typ FET | 2 P-Channel (Dual) Matched Pair |
| FET-Merkmal | Standard |
| Drain-Source-Spannung (Vdss) | 10.6V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | - |

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Sie können auch interessiert

| | | | |
|---|---|--|--|
| <p>sein:</p>  <p>ALD1115PAL Advanced Linear Devices Inc. MOSFET N/P-CH 10.6V 8DIP</p> |  <p>ALD1117PAL Advanced Linear Devices Inc. MOSFET 2P-CH 10.6V 8DIP</p> |  <p>ALD111933PAL Advanced Linear Devices Inc. MOSFET 2N-CH 10.6V 8DIP</p> |  <p>ALD111910SAL Advanced Linear Devices Inc. MOSFET 2N-CH 8SOIC</p> |
|  <p>ALD1116PAL Advanced Linear Devices Inc. MOSFET 2N-CH 10.6V 8DIP</p> |  <p>ALD1115SAL Advanced Linear Devices Inc. MOSFET N/P-CH 10.6V 8SOIC</p> |  <p>ALD111910PAL Advanced Linear Devices Inc. MOSFET 2N-CH 8DIP</p> |  <p>ALD111910MAL Advanced Linear Devices Inc. MOSFET 2N-CH 8MSOP</p> |

Verwandtes Hot-Keyword

Mehr

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|--|--|---|----------------------------------|--|
| ALD1117SAL Advanced Linear Devices, Inc. | ALD1117SAL Datenblatt | ALD1117SAL-Datenblätter | ALD1117SAL PDF | Advanced Linear Devices, Inc. ALD1117SAL |
| ALD1117SAL Electronic | ALD1117SAL-Komponenten | ALD1117SAL-Verteiler | ALD1117SAL-Bild | ALD1117SAL-Teil |
| ALD1117SAL Preis | ALD1117SAL Hersteller | ALD1117SAL Bild | ALD1117SAL Aktie | ALD1117SAL Inventar |
| ALD1117SAL Neu | ALD1117SAL Original | ALD1117SAL garantiert | ALD1117SAL RFQ | ALD1117SAL Online bestellen |

Contact us:Info@Y-IC.com

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